



# N-Channel 12 V (D-S) MOSFET

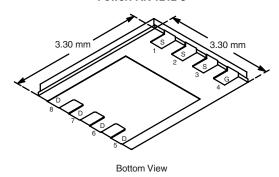
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
12	$0.0057$ at $V_{GS} = 4.5 \text{ V}$	20		
	0.0067 at V <sub>GS</sub> = 2.5 V	18.8		
	0.0085 at V <sub>GS</sub> = 1.8 V	16.5		

# FEATURES

- Halogen-free According to IEC 61249-2-21
  Definition
- TrenchFET<sup>®</sup> Power MOSFET
- New Low Thermal Resistance PowerPAK<sup>®</sup> Package with Low 1.07 mm Profile
- Compliant to RoHS Directive 2002/95/EC



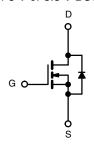
#### PowerPAK 1212-8



Ordering Information: Si7402DN-T1-E3 (Lead (Pb)-free) Si7402DN-T1-GE3 (Lead (Pb)-free and Halogen-free)

## **APPLICATIONS**

- PA Switch, Load Switch and Battery Switch for Portable Devices
- Point-of-Load for 5 V or 3.3 V BUS Stepdown



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T <sub>A</sub> = 25 °C, unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V <sub>DS</sub>	12		V	
Gate-Source Voltage		V <sub>GS</sub>	± 8			
Continuous Dunis Comment /T 150 9C\d	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	20	13		
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		16	10		
Pulsed Drain Current		I <sub>DM</sub>	50		Α	
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	3.2	1.3		
Mariana Barra Birata di ang	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.8	1.5	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		2.4	1.0		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) <sup>b, c</sup>			260			

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Marrian Incation to Ambient	t ≤ 10 s	$R_{thJA}$	24	33	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		65	81	
Maximum Junction-to-Case (Drain)	Steady State	$R_{thJC}$	1.9	2.4	

#### Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (<a href="www.vishay.com/ppg?73257">www.vishay.com/ppg?73257</a>). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

# Vishay Siliconix



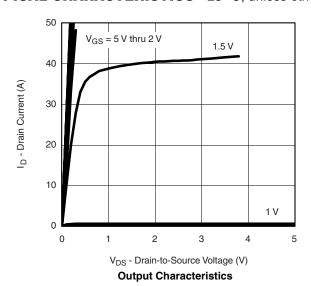
MOSFET SPECIFICATIONS T <sub>J</sub> = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	0.45		0.85	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 12 V, V <sub>GS</sub> = 0 V			1		
		$V_{DS} = 12 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$	5		5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	50			Α	
		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 20 A		0.0045	0.0057	7 Ω	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 2.5 \text{ V}, I_D = 18 \text{ A}$		0.0053	0.0067		
		$V_{GS} = 1.8 \text{ V}, I_D = 10 \text{ A}$		0.0065	0.0085		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 10 \text{ V}, I_{D} = 20 \text{ A}$		100		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 3.2 A, V <sub>GS</sub> = 0 V		0.70	1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_g$			36	55		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 6 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		4		nC	
Gate-Drain Charge	Q <sub>gd</sub>			9.5		ļ	
Gate Resistance	$R_g$			1.8		Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			35	55		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 6 V, $R_L$ = 6 $\Omega$		65	100		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong$ 1 A, $V_{GEN}$ = 4.5 V, $R_g$ = 6 $\Omega$		110	165	ns	
Fall Time	t <sub>f</sub>			60	90		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 2.3 A, dI/dt = 100 A/μs		40	80		

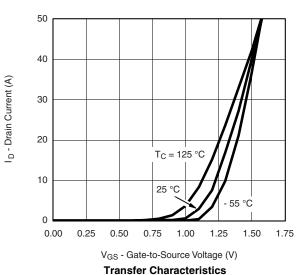
#### Notes:

- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



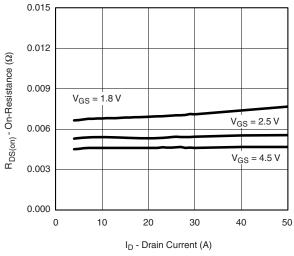


Transfer Characteristics

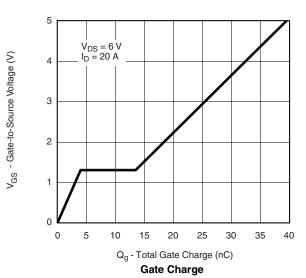


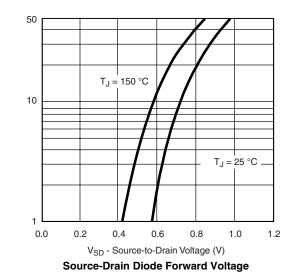


## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



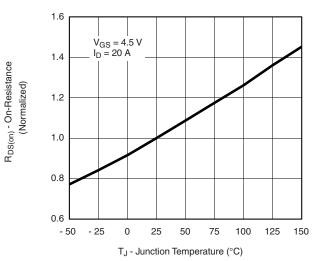
#### **On-Resistance vs. Drain Current**



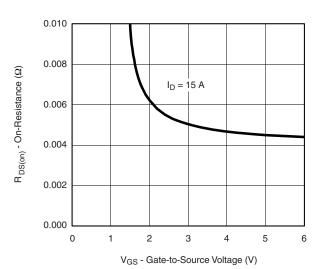


4000  $C_{\text{iss}}$ 3500 3000 C - Capacitance (pF) 2500 2000 1500 Coss 1000 500 0 0 2 6 12 10 V<sub>DS</sub> - Drain-to-Source Voltage (V)

Capacitance



On-Resistance vs. Junction Temperature



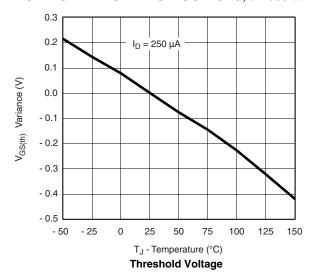
On-Resistance vs. Gate-to-Source Voltage

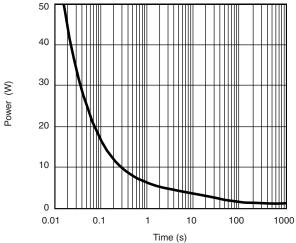
S - Source Current (A)

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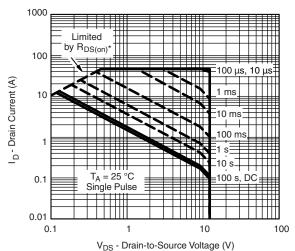
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## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



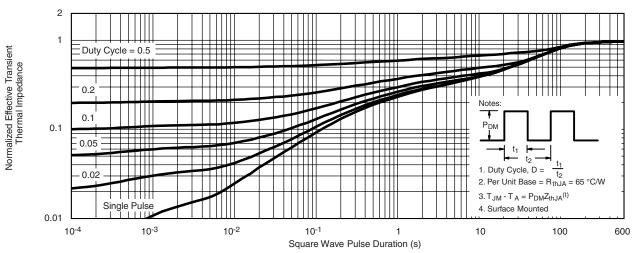


Single Pulse Power, Junction-to-Ambient



\* V<sub>GS</sub> > minimum V<sub>GS</sub> at which R<sub>DS(on)</sub> is specified

#### Safe Operating Area

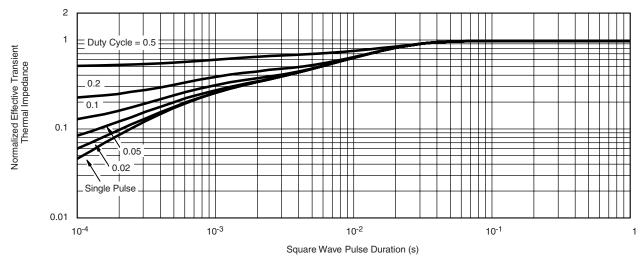


Normalized Thermal Transient Impedance, Junction-to-Ambient





## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

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